

### Very low capacitance ESD protection

#### **Features**

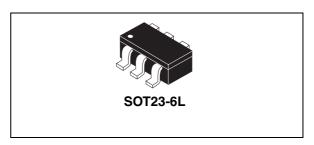
- 4 data lines protection
- Protects V<sub>BUS</sub>
- Very low capacitance: 3 pF typ.
- SOT23-6L package
- RoHS compliant

#### **Benefits**

- Very low capacitance between lines to GND for optimized data integrity and speed
- Low PCB space consumption, 9 mm<sup>2</sup> maximum foot print
- Enhanced ESD protection. IEC 61000-4-2 level 4 compliance guaranteed at device level, hence greater immunity at system level
- ESD protection of V<sub>BUS</sub>. Allows ESD current flowing to Ground when ESD event occurs on data line
- High reliability offered by monolithic integration
- Low leakage current for longer operation of battery powered devices
- Fast response time
- Consistent D+ / D- signal balance:
  - Best capacitance matching tolerance I/O to GND = 0.015 pF
  - Compliant with USB 2.0 requirements1 pF

#### Complies with the following standards

- IEC 61000-4-2 level 4:
  - 15 kV (air discharge)
  - 8 kV (contact discharge)



## **Applications**

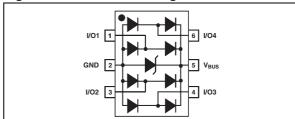
- USB 2.0 ports up to 480 Mb/s (high speed)
- Backwards compatible with USB 1.1 low and full speed
- Ethernet port: 10/100 Mb/s
- SIM card protection
- Video line protection
- Portable electronics

### Description

The **USBLC6-4SC6** is a monolithic application specific device dedicated to ESD protection of high speed interfaces, such as USB 2.0, Ethernet links and video lines.

Its very low line capacitance secures a high level of signal integrity without compromising in protecting sensitive chips against the most stringent characterized ESD strikes.

Figure 1. Functional diagram



Characteristics USBLC6-4

## 1 Characteristics

Table 1. Absolute ratings

Symbol	Parameter		Value	Unit
V <sub>PP</sub>	Peak pulse voltage	IEC 61000-4-2 air discharge IEC 61000-4-2 contact discharge MIL STD883C-Method 3015-6	15 15 25	kV
T <sub>stg</sub>	Storage temperature range		-55 to +150	°C
Тј	Operating junction temperature range		-40 to +125	°C
T <sub>L</sub>	Lead solder temperature (10 seconds duration)		260	°C

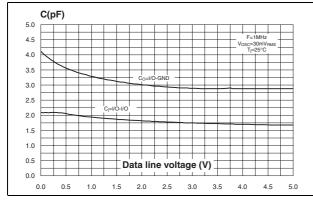
Table 2. Electrical characteristics ( $T_{amb} = 25$  °C)

Cumbal	Dovemeter	Took Conditions	Value			11
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
$V_{RM}$	Reverse stand-off voltage				5	V
I <sub>RM</sub>	Leakage current	V <sub>RM</sub> = 5 V		10	150	nA
V <sub>BR</sub>	Breakdown voltage between V <sub>BUS</sub> and GND	I <sub>R</sub> = 1 mA	6			٧
V <sub>F</sub>	Forward voltage	I <sub>F</sub> = 10 mA			0.86	٧
V <sub>CL</sub>	Clamping voltage	I <sub>PP</sub> = 1 A, 8/20 μs Any I/O pin to GND			12	٧
		I <sub>PP</sub> = 5 A, 8/20 μs Any I/O pin to GND			17	٧
C <sub>i/o-GND</sub>	Capacitance between I/O and GND	V <sub>R</sub> = 1.65 V		3	4	S.E.
$\Delta C_{i/o\text{-GND}}$				0.015		pF
C <sub>i/o-i/o</sub>	Capacitance between I/O	V <sub>R</sub> = 1.65 V		1.85	2.7	pF
ΔC <sub>i/o-i/o</sub>				0.04		ρΓ

USBLC6-4 Characteristics

Figure 2. Capacitance versus voltage (typical values)

Figure 3. Line capacitance versus frequency (typical values)



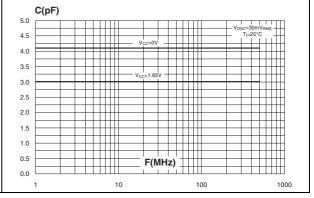
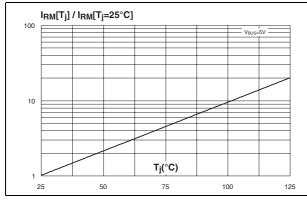
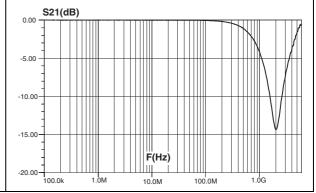


Figure 4. Relative variation of leakage current versus junction temperature (typical values)

Figure 5. Frequency response





Technical information USBLC6-4

### 2 Technical information

### 2.1 Surge protection

The USBLC6-4SC6 is particularly optimized to provide surge protection based on the rail to rail topology.

The clamping voltage V<sub>CL</sub> can be calculated as follows:

$$V_{CI} + = V_{TRANSII} + V_{F}$$
 for positive surges

with: 
$$V_F = V_T + R_d I_p$$

(V<sub>F</sub> forward drop voltage, V<sub>T</sub> forward drop threshold voltage

#### Calculation example

We assume that the value of the dynamic resistance of the clamping diode is typically:

$$R_d = 0.5 \ \Omega$$
 and  $V_T = 1.1 \ V$ .

For an IEC 61000-4-2 surge level 4 (Contact Discharge:  $V_g$  = 8 kV,  $R_g$  = 330  $\Omega$ ),

 $V_{BUS} = +5 \text{ V}$ , and if in a first approximation, we assume that:

$$I_p = V_q / R_q = 24 A.$$

So, we find:

$$V_{CI} + = +31.2 \text{ V}$$

$$V_{CI} - = -13.1 \text{ V}$$

Note: The calculations do not take into account phenomena due to parasitic inductances.

## 2.2 Surge protection application example

If we consider that the connections from the pin  $V_{BUS}$  to  $V_{CC}$ , from from I/O to data line and from GND to PCB GND plane are implemented as racks 10 mm long and 0.5 mm large, we can assume that the parasitic inductances  $L_{VBUS}$   $L_{I/O}$  and  $L_{GND}$  of these tracks are about 6 nH. So, when an IEC 61000-4-2 surge occurs, due to the rise time of this spike ( $t_r = 1$  ns), the voltage  $V_{CL}$  has an extra value equal to  $L_{I/O} \cdot dI/dt$ ,  $+ L_{GND} \cdot dI/dt$ 

The dl/dt is calculated as:

$$dI/dt = I_p/t_r = 24 A/ns$$

The overvoltage due to the parasitic inductances is:

$$L_{I/0} \cdot dI/dt$$
, =  $L_{GND} \cdot dI/dt$  = 6 x 24 = 144 V

By taking into account the effect of these parasitic inductances due to unsuitable layout, the clamping voltage will be:

We can significantly reduce this phenomena with simple layout optimization. It is for this reason that some recommendations have to be followed (see *2.3: How to ensure good ESD protection*).

USBLC6-4 Technical information

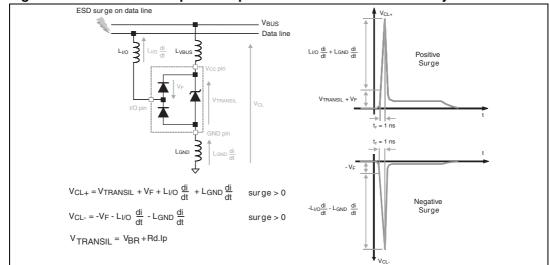
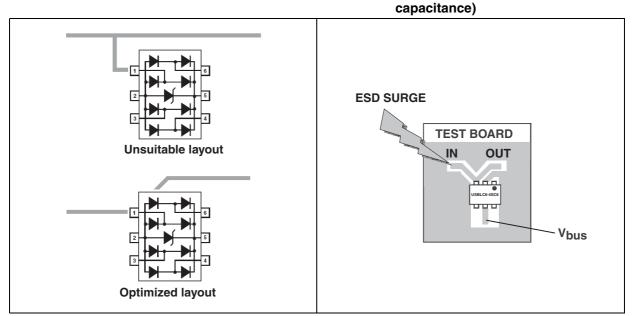


Figure 6. ESD behavior: parasitic phenomena due to unsuitable layout

### 2.3 How to ensure good ESD protection

While the USBLC6-4SC6 provides high immunity to ESD surge, efficient protection depends on the layout of the board. In the same way, with the rail to rail topology, the track from data lines to I/O pins, from  $V_{CC}$  to the  $V_{BUS}$  pin and from GND plane to GND pin must be as short as possible to avoid overvoltages due to parasitic phenomena (see *Figure 7* and *Figure 8* for layout considerations)

Figure 7. ESD behavior: optimized layout and Figure 8. addition of a capacitance of 100 nF conditions (with coupling

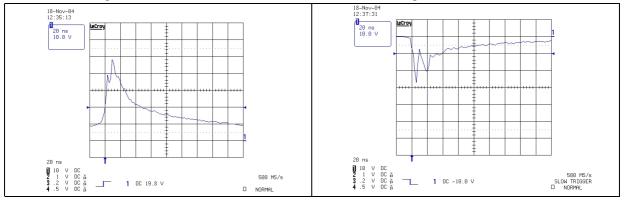


**577** 

Technical information USBLC6-4

Figure 9. Remaining voltage after the USBLC6-4SC6 during positive ESD surge

Figure 10. Remaining voltage after the USBLC6-4SC6 during negative ESD surge



Note: The measurements have been done with the USBLC6-4SC6 in open circuit.

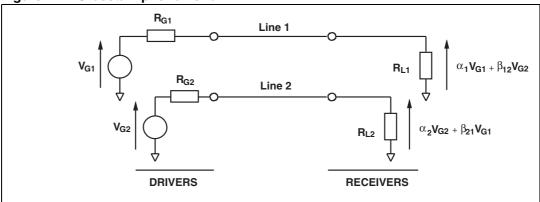
#### Important:

A good precaution to take is to put the protection device as close as possible to the disturbance source (generally the connector).

#### 2.4 Crosstalk behavior

### 2.4.1 Crosstalk phenomenon

Figure 11. Crosstalk phenomenon



The crosstalk phenomenon is due to the coupling between 2 lines. The coupling factor ( $\beta$ 12 or  $\beta$ 21) increases when the gap across lines decreases, particularly in silicon dice. In the above example the expected signal on load  $R_{L2}$  is  $\alpha_2 V_{G2}$ , in fact the real voltage at this point has got an extra value  $\beta_{21} V_{G1}$ . This part of the  $V_{G1}$  signal represents the effect of the crosstalk phenomenon of the line 1 on the line 2. This phenomenon has to be taken into account when the drivers impose fast digital data or high frequency analog signals in the disturbing line. The perturbed line will be more affected if it works with low voltage signal or high load impedance (few  $k\Omega$ ).

6/13

USBLC6-4 Technical information

Figure 12. Analog crosstalk measurements

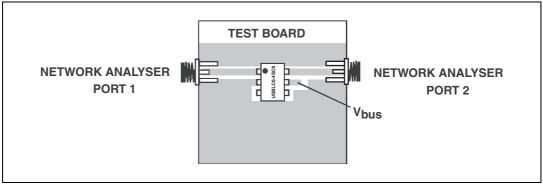
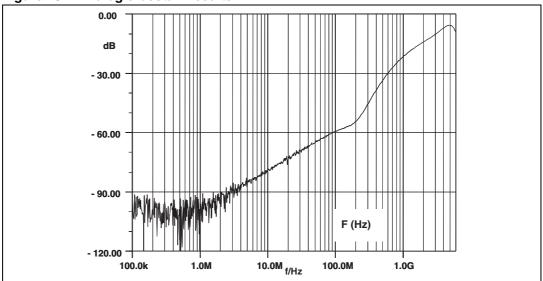


Figure 12. shows the measurement circuit for the analog application. In usual frequency range of analog signals (up to 240 MHz) the effect on disturbed line is less than -55 db ( see Figure 13.).

Figure 13. Analog crosstalk results



As the USBLC6-4SC6 is designed to protect high speed data lines, it must ensure a good transmission of operating signals. The frequency response (*Figure 5.*) gives attenuation information and shows that the USBLC6-4SC6 is well suitable for data line transmission up to 480 Mbit/s while it works as a filter for undesirable signals like GSM (900 MHz) frequencies, for instance.

47/

**Technical information USBLC6-4** 

#### 2.5 **Application examples**

Figure 14. USB 2.0 port application diagram using USBLC6-4SC6

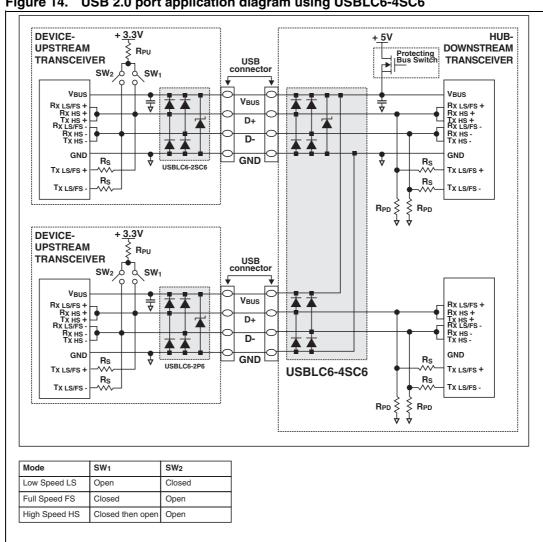
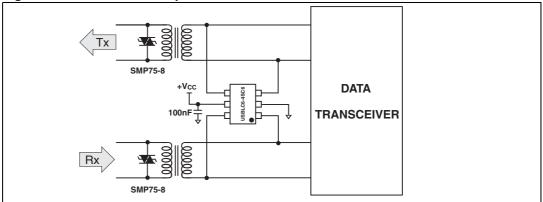


Figure 15. T1/E1/Ethernet protection

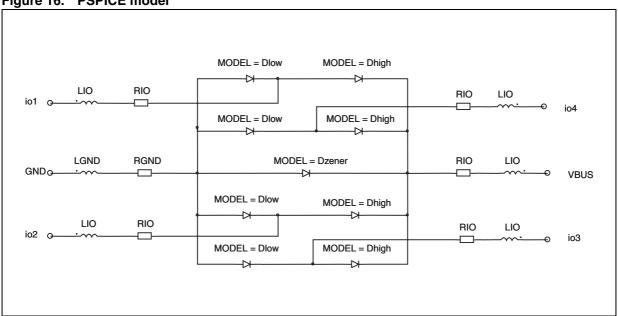


USBLC6-4 Technical information

### 2.6 PSPICE model

*Figure 16.* shows the PSPICE model of one USBLC6-4SC6 cell. In this model, the diodes are defined by the PSPICE parameters given in *Figure 17.* 

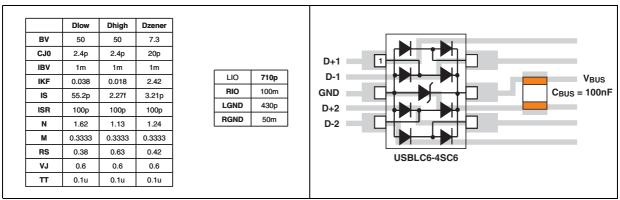
Figure 16. PSPICE model



Note: This simulation model is available only for an ambient temperature of 27 °C.

Figure 17. PSPICE parameters

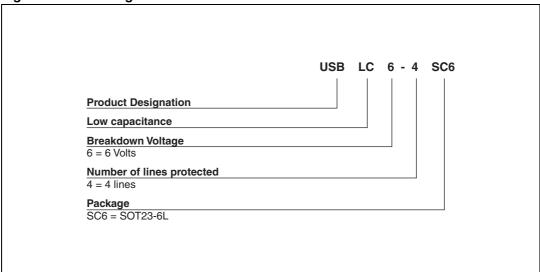
Figure 18. USBLC6-4SC6 PCB layout considerations



**577** 

# 3 Ordering information scheme

Figure 19. Ordering information scheme



USBLC6-4 Package information

## 4 Package information

#### Epoxy meets UL94, V0

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at <a href="https://www.st.com">www.st.com</a>.

Table 3. SOT23-6L dimensions

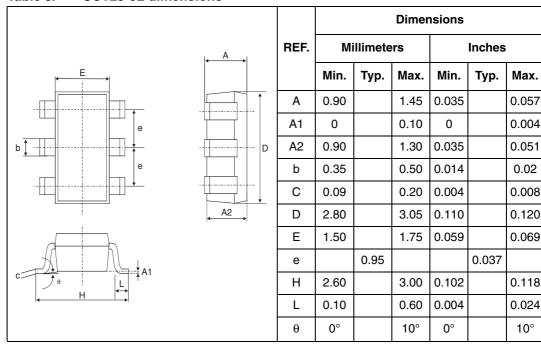
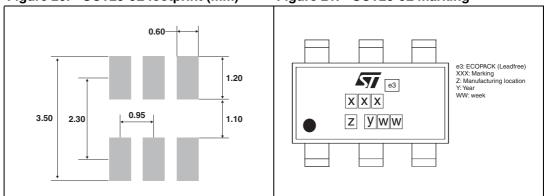


Figure 20. SOT23-6L footprint (mm) Figure 21. SOT23-6L marking



Ordering information USBLC6-4

# 5 Ordering information

Table 4. Ordering information

Ordering code	Marking	Package	Weight	Base qty	Delivery mode
USBLC6-4SC6	UL46	SOT23-6L	16.7 mg	3000	Tape and reel

# 6 Revision history

Table 5. Document revision history

Date	Revision	Description of changes		
10-Dec-2004	1	First issue.		
28-Feb-2005	2	Minor layout update. No content change.		
04-Feb-2008 3		Updated operating junction temperature range in absolute ratings, page 2. Updated <i>Section 2: Technical information</i> . Updated marking illustration <i>Figure 21</i> . Reformatted to current standard.		

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